## COE3DQ5 – Lab #4 Report Group 14

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## a. Changing the original BIST state machine to burst R/W mode

In order to change the SRAM self-test to burst mode, the state between S\_WRITE\_CYCLE and S\_DELAY\_1 & S\_DELAY\_2 is switched. The read mode is turned on 2 clock cycles before the read cycle. Within S\_WRITE\_CYCLE and S\_READ\_CYCLE a compare logic is written to check whether BIST\_address has reached 3FFFE/3FFFF to decide getting to delay state. Correspondingly, BIST\_expected\_data is not assigned to address in combinational logic but incremented by 1 within the state machine to make sure the alignment with BIST\_read\_data.

## b. R/W of SRAM addresses is separated into even and odd

A flag *BIST\_flag* is used to indicate if the next write/read cycle is even or odd. The identification operation is added in S\_IDLE state, where an if statement is utilized to check whether *BIST\_flag* is 0 or 1. When it is 0, *BIST\_address* and *BIST\_expected\_data* is assigned with 0; when it is 1, they are assigned with 1 instead and the increment/decrement will be by 2 rather than 1. At the state when one session of operation is about to finish (S\_DELAY\_3), *BIST\_flag* is inverted.

## c. Write is in increasing order, read is in decreasing order

To achieve writing to addresses in increasing order, when the state is in S\_IDLE, both BIST\_expected\_data and BIST\_address are initialized to 0. Similarly, in S\_WRITE\_CYCLE both two signals are incremented by 2. On the other hand, to reach the fact that reading the address in decreasing order, when writing operation is finished and state enters S\_DELAY\_1 BIST\_address and BIST\_expected\_data are assigned with (3FFFE & FFFE) or (3FFFF & FFFF). When reading them, a subtraction by 2 is performed instead.